

EAST - [resistor.wsp.1]

File View Edit Tools Window Help

☐ Drafts
☒ Pending
☐ Active

L1: (141563) magnetic.clm.
 L2: (9333) 1 and (MTJ or (magnetic adj2 junction))
 L3: (39) 2 and ((implant\$3 or diffus\$3 or dop\$3) near10 (magnetic
 L4: (95) 2 and ((implant\$3 or diffus\$3 or dop\$3) near10 (magnetic
 L5: (68) 2 and (implant\$3 or diffus\$3 or dop\$3).clm.
 L6: (45) 5 and (implant\$3.clm. or doping.clm. or diffusion.clm.)
 L7: (30) 6 and (magnetic adj2 (layer\$1 or film\$1)).clm.
 L8: (4049) 1 and (MTJ or (magnetic adj2 junction) or (magnetic adj
 L9: (29) 8 and (diffusion near3 (component\$1 or element\$1))
 L10: (54) 8 and (diffusion near3 (component\$1 or element\$1 or atom
 L11: (8) 10 and (diffusion near3 (component\$1 or element\$1 or atom

Failed

Saved

(0) ("(thinadjfilm)nearresistor").PN.
 (0) ("(thinadjfilm)nearresistor").PN.
 (150130) thin adj film
 (14857) (thin adj film) and resistor
 (2054) ((thin adj film) and resistor) and ((thin adj film) near res

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	U	I	P	T	P	Document ID	Issue Dat	Pages	Title	Current OR	Current KR	Retrieval	Inventor	S	C	J	
1	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040109339	20040610	13	MRAM memories utilizing	365/98			Tsang, David	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
2	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040095813	20040520	46	Semiconductor	365/200			Hosotani, Keiji	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
3	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040076036	20040422	25	integrated circuit devi	365/173			Heide, Carsten	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
4	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040008556	20040115	33	Magnetic memory device	365/210	365/158,		Hidaka, Hideto	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
5	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030911	20030911	11	Memory device reading	438/689	365/173		Hwang, Jeng H. et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
6	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030170985	20030605	27	Etching methods for a	365/200	257/E43.00		al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
7	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030103393	20030605	27	magnetic memory cell st	365/200	6		Asao, Yoshiaki	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
8	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030086313	20030509	25	Magnetic memory device	365/200			Asao, Yoshiaki	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
9	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030076707	20030424	13	and method for manufact	365/158	257/E27.00		Kim, Dong-wook et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
10	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030062553	20030403	17	using SOI substrate and	257/295	5		al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
11	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20011115	20011115	21	Epitaxial template and	360/324.2	257/E45.00		Ramesh,	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
12	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20010040778	20010927	5	barrier for the integra	365/200	1:		Ramamoorthy et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
13	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20010024388	20040706	32	LIMITING	365/171	365/158,		ABRAHAM, DAVID	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
14	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6760251			MAGNETORESISTIVE ELECTR				WILLIAM et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
15	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>				Magnetoresistive				Schwarzl,	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
16	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>				element and use thereof				Siegfried	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
17	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>				Memory device reading				Hidaka, Hideto	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>